

Scilab Textbook Companion for  
Electronic Devices And Circuits  
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July 31, 2019

<sup>1</sup>Funded by a grant from the National Mission on Education through ICT, <http://spoken-tutorial.org/NMEICT-Intro>. This Textbook Companion and Scilab codes written in it can be downloaded from the "Textbook Companion Project" section at the website <http://scilab.in>

# Book Description

**Title:** Electronic Devices And Circuits

**Author:** K. L. Kishore

**Publisher:** BS Publications, Hyderabad

**Edition:** 1

**Year:** 2008

**ISBN:** 81-7800-167-5

Scilab numbering policy used in this document and the relation to the above book.

**Exa** Example (Solved example)

**Eqn** Equation (Particular equation of the above book)

**AP** Appendix to Example(Scilab Code that is an Appednix to a particular Example of the above book)

For example, Exa 3.51 means solved example 3.51 of this book. Sec 2.3 means a scilab code whose theory is explained in Section 2.3 of the book.

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# Chapter 1

## Electron Dynamics and CRO

Scilab code Exa 1.1 speed of electron in electric field

```
1 // Example 1.1 page no-4
2 clear
3 clc
4
5 //(1)
6 V=10
7 d=5*10^-2
8 t=50*10^-9
9 T=10^-7
10 x=1.76*10^11
11 eps=V/(d*T)
12 a=x*eps
13 v=a*t^2/2
14 printf("\n(1)\nVelocity , v = %.1f*10^5 m/s\n",v
        /100000)
15
16 //(2)
17 x1=(a/6)*(t^3)
18 printf("\n(2)\ndistance , x=%f cm\n",x1*100)
19
20 //(3)
```

```

21 x2=0.05
22 t1=(x2/(a/6))^(1/3)
23 v1=(a/2)*t1^2
24 printf("\n(3)\nspeed with which the electron strikes
        the positive plate,\nv = %.2f*10^6 m/sec",v1
        /10^6)

```

---

**Scilab code Exa 1.2** speed of electron and position of applied AC voltage point

```

1 // Example 1.2 page no-9
2 clear
3 clc
4
5 e=1.6*10^-19//C
6 m=9.1*10^-31//kg
7 Vmax=1.5 //v
8 w=2*%pi*60*10^6//rad/sec
9 d=8*10^-3 //m
10 Max_Vel=2*e*Vmax/(m*d*w)
11 Max_Vel=ceil(Max_Vel*10^-3)
12 printf("The Maximum value of Velocity is , \n dx/dt=%
        .2f*10^5 m/sec",Max_Vel/100)

```

---

**Scilab code Exa 1.3** effect of electric field on electron

```

1 // Example 1.3 page no-10
2 clear
3 clc
4
5
6 //(1)
7 eps=(2000)/3 //V/cm
8 e=1.6*10^-19 //C

```

```

9 m=9.1*10^-31 //kg
10 v= 10^7 // dy/dt=v m/sec
11 t=v*m/(e*eps*100)
12 t=floor(t*10^11)
13 t=t/10
14 printf("\n(1)\nTime ,t=%0.1f*10^-10 sec\n",t)
15 t=t*10^-10
16 //(2)
17 y=(e*eps*100*t^2)/(2*m)
18 printf("\n(2)\nDistance travelled by electron , y=%f
    m\n",y)
19 //(3)
20 pd=eps*100*y
21 printf("\n(3)\nPotential Drop=%0.1f Volts",pd)

```

---

#### Scilab code Exa 1.4 calculation of potential

```

1 // Example 1.4 page no-13
2 clear
3 clc
4 V0=10 //volts siince energy is 10ev
5 xm=2
6 theta=%pi/4
7 V=(2*V0*sin(2*theta))/xm
8 printf("V=%0.0fd Volts",V)

```

---

#### Scilab code Exa 1.5 Application of magnetic field on electron

```

1 // Example 1.5 page no-19
2 clear
3 clc
4
5 B=0.03 //wb/m^2

```

```

6 m=9.1*10^-31 //kg
7 V=2*10^5
8 e=1.6*10^-19 //C
9
10 R=(2*m*V/e)^(1/2)
11 R=floor(R*100/B)
12 printf("Radius of the circle , R=%0f cm",R)
13 //OAC is a right angled triangle
14 oa=R
15 oc=3
16 ac=sqrt((oa)^2-(oc)^2)
17 printf("\n AD=%d cm",oa-ac)

```

---

#### Scilab code Exa 1.6 calculation of transit time

```

1 // Example 1.6 page no-20
2 clear
3 clc
4
5 m=9.1*10^-31 //kg
6 V=100
7 e=1.6*10^-19 //C
8 d=5*10^-2 //m
9 t=10^-8 //sec
10 d1=(e*V*t^2)/(m*d*2)
11 d2=(5-d1*100)
12 printf("\nd1=%0.3 f*10^-2m\nd2=%0.2 f*10^-2m",d1*100,d2)
13 t1=0.01*10^-6 ///sec
14 v1=e*V*t1/(m*d)
15 v1=ceil(v1/10^4)
16 printf("\nVelocity of Electron ,v=%0.2 f*10^6m/s",v1
/100)
17 t2=(d2*10^-2)/(v1*10^4)
18 printf("\nt2=%0.1 f*10^-8 sec",t2*10^8)
19 printf("\nTotal transit time =t1+t2=%0.1 f*10^-8 sec"

```

,(t1/10<sup>-8</sup>)+t2\*10<sup>8</sup>)

---

#### Scilab code Exa 1.7 time of flight under electric field

```
1 // Example 1.7 page no-20
2 clear
3 clc
4
5 V=1000 // volt
6 d=0.01 //m
7 e=1.6*10-19 //C
8 m=9.1*10-31 //kg
9 eps=V/d
10 t=sqrt((2*m*d)/(e*eps))
11 printf("t=%0.2 f*10-9",t*1010)
```

---

#### Scilab code Exa 1.8 velocity of electron

```
1 // Example 1.8 page no-21
2 clear
3 clc
4
5 V=1000 // volt
6 e=1.6*10-19 //C
7 m=9.1*10-31 //kg
8 Vf=sqrt((2*e*V)/m)
9 printf("V_final=%0.2 f*106 m/sec",Vf/106)
```

---

#### Scilab code Exa 1.9 application of electric and magnetic field

```

1 // Example 1.9 page no-24
2 clear
3 clc
4
5 k=1.76*10^11 ///e/m in C/kg
6 eps=10^4
7 B=0.01
8
9 Xmax=2*eps*pi/((B^2)*k)
10 printf("Xmax=%0.3 f cm", Xmax*100)

```

---

Scilab code Exa 1.10 distance travelled in helical path

```

1 // Example 1.10 page no-25
2 clear
3 clc
4
5 Energy=50 //eV
6 V0=Energy //Volts
7 e=1.6*10^-19 //c
8 m=9.1*10^-31 //kg
9 v0=sqrt(2*e*V0/m)
10 v0=ceil(v0/10^5)
11 v0=(v0/10)*10^6
12 printf("\nVelocity , v0=%0.0 f", v0)
13
14 t=(35.5*10^-12)/(2*10^-3)
15 //Components of velocities are
16 v1=v0*cos(10*pi/180)
17 v2=v0*cos(20*pi/180)
18 x=v1-v2
19 d=x*t
20 printf("\nDistance , d =%0.4 f cm", d*100)

```

---

### Scilab code Exa 1.11 Deflection sensitivity

```
1 // Example 1.11 page no-33
2 clear
3 clc
4
5 l=2 //cm
6 D=18 //cm
7 s=0.5 //cm
8
9 //(a)
10 va1=500 //volts
11 ds1=1*D/(2*s*va1) // Deflection Sensitivity
12 //(b)
13 va2=1000 //Volts
14 ds2=1*D/(2*s*va2)
15 //(c)
16 va3=1500 //Volts
17 ds3=1*D/(2*s*va3)
18 printf("\n(a) Va=%dV\nDeflection Sensitivity S_E=%0.3 f
        cm/V \n\n(b) Va=%dV\nDeflection Sensitivity S_E=%
        .3 f cm/V\n\n(c) Va=%dV\nDeflection Sensitivity S_E
        =%0.3 f cm/V", va1, ds1, va2, ds2, va3, ds3)
```

---

### Scilab code Exa 1.12 displacement angle and velocity of electron in CRT

```
1 // Example 1.12 page no-34
2 clear
3 clc
4
5 l=2 //cm
6 D=24 //cm
```



```

7 s=0.5 //cm
8 Vd=30 //Volts
9 Va=1000 //Volts
10
11 //(a)
12 d=Vd*l*D/(2*s*Va)
13 printf("\n(a)\nDeflection Produce , d=%0.2 f cm\n",d)
14
15 //(b)
16 theta=(atan(d/D))*(180/%pi)
17 printf("\n(b)\nTheta=%0.2 f ",theta)
18 //(c)
19 e=1.6*10^-19 //C
20 m=9.1*10^-31 //kg
21 v=sqrt(2*e*Va/m)
22 vr=v/cos(theta*%pi/180)
23 printf("\n\n(c)\nResultant Velocity , Vr=%0.2 f *10^6 m
    /sec",vr/10^6)

```

---

### Scilab code Exa 1.13 Calculation of transverse magnetic field

```

1 // Example 1.13 page no-34
2 clear
3 clc
4
5 l=1.27 //cm
6 D=19.4 //cm
7 s=0.475 //cm
8 Va=400 //volts
9 Se=l*D*10^-2/(2*s*Va)
10 Se=ceil(Se*10^5)
11 printf("\nS_E=%0.2 f mm/v",Se/100)
12
13 v=30 //volt
14 e=1.6*10^-19 //C

```

```

15 m=9.1*10^-31 //kg
16 x=sqrt(m/e)
17 B=(x*0.65*30*sqrt(2*Va))/(1*D)
18 printf("\nB=%0.2f*10^-5 wb/m^2",B*10^5)//answer not
    matches with given answer

```

---

Scilab code Exa 1.14 effect of earths magnetic field on deflection in CRT

```

1 // Example 1.14 page no-35
2 clear
3 clc
4
5 v0=1.19*10^7 //m/sec
6 B=0.6*10^-4 //wb/m^2
7 v=400
8 //Radius of the circle described by the electron due
    to earth magnetic field
9 R=3.37*10^-6*sqrt(v)/B
10 printf("\nRadius of Circle , R=%0.2fm",R)
11 y=sqrt((112)^2-20^2)
12 y=112-y
13 printf("\ndeflection of the electron on the screen ,
    y=%0.1f cm",y)

```

---

## Chapter 2

# Junction Diode Characteristics

Scilab code Exa 2.1 radius of the lowest state of Ground State

```
1 // Example 2.1 page no-45
2 clear
3 clc
4
5 n=1
6 h=6.626*10^-34 //J-sec
7 eps=10^-9/(36*pi)
8 m=9.1*10^-31 //kg
9 e=1.6*10^-19
10 r=n^2*h^2*eps/(pi*m*e^2)
11 printf("\nradius of the lowest state of Ground State
    , r=%0.2f A ",r*10^10)
```

---

Scilab code Exa 2.2 no of photons emitted per second by lamp

```
1 // Example 2.2 page no-46
2 clear
3 clc
```

```

4
5 lambda=2537 // A
6 E_diff=12400/lambda
7 e=1.6*10^-19
8 energy=50/1000 //J/sec
9 e_j=energy/e //eV/sec
10 n=e_j/E_diff
11 printf("The lamp emits %.1f *10^16 photons/sec of
        wavelength , lambda=%dA " ,n/10^16,lambda)

```

---

### Scilab code Exa 2.3 Speed of ejected electron

```

1 // Example 2.3 page no-47
2 clear
3 clc
4 e_ar=11.6 //eV
5 e_Na=5.12 //eV
6 V=e_ar-e_Na
7 e=1.6*10^-19 //C
8 m=9.1*10^-31 //kg
9 v=sqrt(2*e*V/m)
10 printf(" Velocity , v=%.2f*10^6 m/sec" ,v/10^6)

```

---

### Scilab code Exa 2.4 speed of electron in sodium vapour lamp

```

1 // Example 2.4 page no-48
2 clear
3 clc
4
5 l=5893 // A
6 V=2.11 //Volts
7 e=1.6*10^-19 //C
8 m=9.1*10^-31 //kg

```

```

9 v=sqrt(2*e*V/m)
10 printf(" Velocity , v=%0.2 f*10^5 m/sec" ,v/10^5)

```

---

### Scilab code Exa 2.5 radio transmitter

```

1 // Example 2.5 page no-48
2 clear
3 clc
4
5 f=10*10^6 //Hz
6 h=6.626*10^-34 //Joules/sec
7 e=1.6*10^-19 //C
8 //(a)
9 E=h*f/e
10 printf("\n(a) Energy of each radiated quantum ,\n\tE=%0.3 f*10^-27 Joules/Quantum\n\tE=%0.2 f*10^-8 eV/Quantum" ,h*f*10^27 ,E*10^8)
11
12 //(b)
13 E=1000 //Joule/sec
14 N=E/(h*f)
15 printf("\n\n(b)\nTotal number of quanta per sec , N=%0.2 f*10^29" ,N/10^29)
16
17 //(c)
18 o=10^-7
19 printf("\n\n(c)\nNumber of quanta emitted per cycle = %0.2 f*10^22 per cycle" ,o*N/10^22)

```

---

### Scilab code Exa 2.6 Neon Ionization

```

1 // Example 2.6 page no-48
2 clear

```

```

3  clc
4
5  //(a)
6  V=21.5 //Volts
7  e=1.6*10^-19 //C
8  m=9.1*10^-31 //kg
9  v=sqrt(2*e*V/m)
10 lambda=12400/V // A
11 printf("\n(a)\nVelocity , v=%0.2f*10^6 m/sec\n
        nWavelength of Radiation , Lambda=%0.1f",v/10^6,
        ceil(lambda))
12 //(b)
13 c=3*10^8 //m/sec
14 f=c/(lambda*10^-10)
15 printf("\n(b)\nFrequency of Radiation , f=%0.1f*10^15
        Hz",f/10^15)

```

---

#### Scilab code Exa 2.8 wavelength of photon

```

1 // Example 2.8 page no-49
2 clear
3 clc
4 L=1400
5 E_diff=12400/L //eV
6 del_E=2.15
7 L2=12400/del_E
8 printf("\nE2-E1=%0.2f eV\n1850 A line is from 6.71
        eV to 0 eV\nTherefore , second photon must be from
        %0.2f to 6.71 eV.\nLambda=%0d A .",E_diff,E_diff,
        L2)

```

---

#### Scilab code Exa 2.9 High field emission

```

1 // Example 2.9 page no-58
2 clear
3 clc
4 A=60.2*10^4 //A/m^2/ K ^2
5 B=52400 // K
6 T1=2400 // K
7 T2=2410 // K
8 js1=A*T1^2*(%e^(-B/T1))
9 js2=A*T2^2*(%e^(-B/T2))
10 js1=floor(js1)
11 js2=floor(js2)
12 printf("\nJS1=%d A/m^2\nJS2=%d A/m^2",js1,js2)
13 p=(js2-js1)*100/js1
14 printf("\nPercentage Increase=%0.2f%%",p)

```

---

#### Scilab code Exa 2.10 Work function and wavelength

```

1 // Example 2.10 page no-58
2 clear
3 clc
4
5 //(a)
6 h=6.63*10^-34 //Plank's Constant, J sec.
7 e=1.6*10^-19 //Charge of Electron, C
8 c=3*10^8 //Velocity of Light, m/sec
9 v=0.55 //volts
10 l=5500*10^-10 //m
11 fi=(h*c)/(l*e)
12 fi=fi-v
13 printf("\n(a)\nWork Function(WF), fi=%0.2f Volts",fi)
14 //(b)
15 l0=12400/fi
16 printf("\n\n(b)\nThreshold Wavelength = %d A ",l0)

```

---

### Scilab code Exa 2.11 effect of temperature on emission

```
1 // Example 2.11 page no-59
2 clear
3 clc
4 dT=20
5 T=2310 // K
6 Ew=4.52
7 k=8.62*10^-5
8 x=(Ew/(k*T))
9 x=(2+x)*dT/T
10 printf("\n(a)\ndIth/Ith=%0.1f%%\n\n(b)\nThis is
        solved by Trial and Error Method to get T = 2370
        K ",x*100)
```

---

### Scilab code Exa 2.12 RF voltage frequency in cyclotron

```
1 // Example 2.12 page no-60
2 clear
3 clc
4
5 B=1 //Tesla
6 T=35.5*10^-6 //sec
7 f=1/T
8 printf("\n(a)\nThe frequency of the R.F voltage , f=%
        .2f*10^4 Hz",f/10^4)
9 k=2*10^6
10 g=40000
11 printf("\n\n(b)Number of passages required to gain
        2*10^6 eV are ,N=%d",k/g)
12 v=49*g
13 R=(3.37*10^-6)*sqrt(v)
```



```
14 printf("\n\n(c)\nDiameter of last semicircle , D = 2R
    =%.2f *10^-4 m", 2*R*10000)
```

---

### Scilab code Exa 2.13 Emission current and cathode efficiency

```
1 // Example 2.13 page no-60
2 clear
3 clc
4 Ew=1 //eV
5 A0=100 // A/m2 I K2
6 S=1.8*10^-4 //cm2
7 K =8.62 * 10^-5 //eV/oK
8 T=1100
9 pd=5.8*10^4 //W/m^2
10 ipd=1.1*pd
11 tip=S*ipd
12 Ith=S*A0*T^2*%e^(-Ew/(K*T))
13 printf("\nIth=%.3f A\nCathode Efficiency , eta=%.0f
    mA/ K ", Ith, ceil(Ith*1000/11.5))
```

---

### Scilab code Exa 2.14 resistivity of doped material

```
1 // Example 2.14 page no-71
2 clear
3 clc
4
5 n=4.4*10^22 //cm^3
6 mu=3600 //cm62/volt-sec
7 e=1.6*10^-19 //C
8 sigma=n*mu*e*10^-6
9 printf("\nResistivity , rho=%.3f Ohm-cm", 1/sigma)
```

---

Scilab code Exa 2.15 conductivity and resistivity of pure silicon

```
1 // Example 2.15 page no-71
2 clear
3 clc
4 mup=500
5 mun=1500
6 n=1.6*10^10
7 e=1.6*10^-19 //c
8 sigma=(mun+mup)*e*n
9 printf("\nconductivity , sigma=%0.2f *10^-6\
      nResistivity , rho= %d Ohm-cm",sigma*10^6,1/sigma)
```

---

Scilab code Exa 2.16 concentration of free electrons and holes

```
1 // Example 2.16 page no-71
2 clear
3 clc
4
5 A = 9.64 * 10^14
6 EG = 0.25 //eV
7 n1 = 6.25*10^26 ///cm^3
8 na=3*10^14
9 nd=2*10^14
10 n=-(10^14)+(sqrt(10^28+4*6.25*10^26))
11 n=n/2
12 printf("\nn=%0.1f*10^12 electrons/cm^3\nnp=%0.2f*10^14
      holes/cm^3\nAs p> n, this is p-type semiconductor
      .",n/10^12,(n+10^14)/10^14)
```

---

**Scilab code Exa 2.17** concentration of free electrons and holes

```
1 // Example 2.17 page no-72
2 clear
3 clc
4 sigma=100 //Ohm-cm
5 e=1.6*10^-19 //c
6 mup=1800 //cm^2/V-sec
7 ni=2.5*10^13 // /cm^3
8 printf("\nIn p-type semiconductor, p>>n.")
9 pp=sigma/(e*mup)
10 n=ni^2/pp
11 printf("\nPp=%0.2f*10^17 holes/cm^3\nn=%0.1f*10^9
    electrons/cm^3",pp/10^17,n/10^9)
```

---

**Scilab code Exa 2.18** concentration of free electrons and holes in p type Ge and n

```
1 // Example 2.18 page no-72
2 clear
3 clc
4
5 //(a)
6 sigma=100 //Ohm-cm
7 e=1.6*10^-19 //c
8 mup=1800 //cm^2/V-sec
9 ni=2.5*10^13 // /cm^3
10 printf("\n(a)\nAs it is p-type semiconductor, p>>n."
    )
11 pp=sigma/(e*mup)
12 n=ni^2/pp
13 printf("\nPp=%0.2f*10^17 holes/cm^3\nn=%0.1f*10^9
    electrons/cm^3",pp/10^17,n/10^9)
14
15 //(b)
16 mun=1300
```

```

17 sig=0.1
18 n1=1.5*10^10
19 n2=sig/(mun*e)
20 p1=(n1^2)/n2
21 printf("\n\n(b)\nnn=%0.2f*10^14 electrons/cm^3\nnp=%0.2f
    *10^5 holes/cm^3",n2/10^14,p1/10^5)

```

---

Scilab code Exa 2.19 conduction current density

```

1 // Example 2.19 page no-73
2 clear
3 clc
4 sig=1/60 // v/cm
5 mup=1800 //cm^2/V-sec
6 mun=3800 //cm^2/V-sec
7 e=1.6*10^-19 //C
8
9 ni=sig/(e*(mun+mup))
10 na=7*10^13 //cm^3
11 nd=10^14 // /cm^3
12 k=na-nd //p-n
13 p=0.88*10^13
14 n=3.88*10^13
15 eps=2
16 J=(n*mun+p*mup)*(e*eps)
17 printf("J=%0.1f mA/cm^3",J*1000)

```

---

Scilab code Exa 2.20 concentration of free electrons and holes in Ge

```

1 // Example 2.20 page no-74
2 clear
3 clc
4 na=3* 10^14 // /cm^3

```

```

5 nd= 2*10^14 // /cm^3
6 ni= 2.5*10^13 // /cm^3
7
8 k=na-nd
9 n=(-k+sqrt(k^2+4*ni^2))/2
10 printf("\nn=%0.1f*10^18 electrons/m^3\np=%0.2f*10^19
        holes/m^3\n\nas p > n, it is p-type semiconductor
        ",n/10^12,ni^2/n*10^-13)

```

---

**Scilab code Exa 2.21** intrinsic concentration and conductivity of Germanium

```

1 // Example 2.21 page no-75
2 clear
3 clc
4
5 A=9.64*10^21
6 T=320
7 e=1.6*10^-19
8 Eg=0.75
9 k=1.37*10^-23
10 ni=A*T^(3/2)*%e^(-(e*Eg)/(2*k*T))
11 printf("\nni=%0.2f *10^19 electrons (holes)/m^3",ni
        /10^19)
12 mup=0.36
13 mun=0.17
14 sig=e*ni*(mup+mun)
15 printf("\nConductivity , Sigma=%0.3f Mho/m",sig)

```

---

**Scilab code Exa 2.22** resistivity of intrinsic Germanium at room temperature

```

1 // Example 2.22 page no-75
2 clear
3 clc

```

```

4
5 e=1.6*10^-19//C
6 ni=2.5*10^19
7 mun=0.36 //m^2/V-sec
8 mup=0.17 //m^2/V-sec
9 sig=e*ni*(mup+mun)
10
11 rho=1/sig
12 printf(" Resistivity , rho=%0.2f Ohm-m" ,rho)

```

---

#### Scilab code Exa 2.23 Fermi level of p type Ge

```

1 // Example 2.23 page no-80
2 clear
3 clc
4 mup=0.4
5 T=300
6 Nv=4.82*10^15
7 Na=Nv*mup^(3/2)*T^(3/2)
8 printf("\nDoping concentration , NA=%0.2f*10^18 atoms/
   cm^3" ,Na/10^18)

```

---

#### Scilab code Exa 2.24 Distance of Fermi level from centre of forbidden band

```

1 // Example 2.24 page no-80
2 clear
3 clc
4 Vt=0.026
5 Nv=(3/4)*Vt*log(2)
6 printf("\nFor Intrinsic Semiconductor,\nEF will be
   at the centre of the forbidden band. \nBut if mp
   and mn are unequal, EF will be away\nfrom the

```

centre of the forbidden band by  
 $N_v = 0.1 f * 10^{-3} \text{ eV}$ ,  $N_v * 10^3$ )

---

**Scilab code Exa 2.25** Temperature for which conduction band and fermi level coincide

```
1 // Example 2.25 page no-83
2 clear
3 clc
4
5 si=5*10^22 //atom/cm^3
6 d=2*10^8
7 Nd=si/d
8 m=9.1*10^-31//kg
9 k=1.38*10^-23
10 h=6.626*10^-34
11 Nc=2*(2*pi*m*k/h^2)^(3/2)
12 T=(Nd/Nc)^(2/3)
13 printf("T=%0.2 f K ",T*10^4) //Nd/10^14)
```

---

**Scilab code Exa 2.26** distance between valence band and Fermi level

```
1 // Example 2.25 page no-83
2 clear
3 clc
4
5 m=9.1*10^-31//kg
6 k=1.38*10^-23
7 h=6.626*10^-34
8 T=300
9 mp=0.6
10 si=5*10^22
11 at=10^8
12 Nc=si/at
```

```

13 Nv=2*(2*pi*m*k*T*mp/h^2)^(3/2)
14 printf("\nNv=%0.2 f * 10^19 /cm^3",Nv/10^25)
15 Kt=0.026
16 Ediff=Kt*log(1.17*10^19/(5*10^14))
17 printf("\nEf-Ev =%0.2 f eV\nTherefore , EF is above Ev"
        ,Ediff)

```

---

**Scilab code Exa 2.27** doping concentration for given fermi level

```

1 // Example 2.27 page no-86
2 clear
3 clc
4 mp=0.4
5 T=300
6 k=4.82*10^15
7 Nv=k*(mp*T)^(3/2)
8 printf("Doping concentration , NA = ND = %0.2 f*10^18
        atoms/cm^3",Nv/10^18)

```

---

**Scilab code Exa 2.28** Distance of Fermi level from centre of forbidden band

```

1 // Example 2.28 page no-86
2 clear
3 clc
4 Vt=0.026
5 Nv=(3/4)*Vt*log(3)
6 printf("\nFor Intrinsic Semiconductor,\nEF will be
        at the centre of the forbidden band. \nBut if mp
        and mn are unequal, EF will be away\nfrom the
        centre of the forbidden band by\n\nNv=%0.1 f*10^-3
        eV",Nv*10^3)

```

---



### Scilab code Exa 2.29 Einstein relationship

```
1 // Example 2.29 page no-90
2 clear
3 clc
4 mung=3800
5 mupg=1800
6 muns=1300
7 mups=500
8 Vt=0.026
9 printf("\nFor Germanium at room temperature, \nDp=%d
   cm^2/sec \nDn=%d cm^2/sec \n\nFor Silicon, \nDp=%d
   cm^2/sec \nDn=%d cm^2/sec", ceil(mupg*Vt), ceil(mung
   *Vt), ceil(mups*Vt), ceil(muns*Vt))
```

---

### Scilab code Exa 2.30 Hall Effect

```
1 // Example 2.30 page no-95
2 clear
3 clc
4
5 B=0.1 //Wb/m^2
6 Vh=50 //mV
7 I=10 //mA
8 rho=2*10^5 //Ohm-cm
9 w=3*10^-3 //m
10 x=B*I*10^-3/(Vh*10^-2*w)
11 printf("\n1/RH=%0.3 f", x)
12 y=1/(rho*10^-2)
13 printf("\nConductivity = %f mhos/meter \nmu=%0 f cm
   ^2/V-sec", y, (y/x)*10^6)
```

---

### Scilab code Exa 2.31 Reverse saturation current in diode

```
1 // Example 2.31 page no-116
2 clear
3 clc
4
5 //(a)
6 Vt=300/11600
7 v=Vt*log(1.9)
8 printf("\n(a)\nV=%0.3fV",v)
9
10 //(b)
11 v1=0.2
12 i1=10*(%e^(v1/Vt)-1)
13 printf("\n(b)\nFor V=0.2, I=%0.2f mA",i1/1000)
14 v2=0.3
15 i2=10*(%e^(v2/Vt)-1)
16 printf("\n\nFor V=0.3, I=%0.2f A",i2/1000000)
```

---

### Scilab code Exa 2.32 AC and DC resistance of Ge diode

```
1 // Example 2.32 page no-116
2 clear
3 clc
4
5 Vt=301.6/11600
6 i0=20*10^-6
7 v=0.1
8 I=i0*(%e^(v/Vt)-1)
9 printf("\nI=%0.3f mA",I*1000)
10 r_DC=v/I
11 printf("\nr_DC=%0.1f Ohm",r_DC)
```

```

12 r_AC=i0*(%e^(v/Vt))/Vt
13 printf("\nr_AC = %.1 f Ohm" ,1/r_AC)

```

---

Scilab code Exa 2.33 width of the depletion layer

```

1 // Example 2.33 page no-117
2 clear
3 clc
4
5 A = 0.001 // cm2
6 sig1n= 1 //mhos/cm,
7 sig1p=100 //mhos/cm
8 mun=3800 //cm2/sec
9 mup = 1800 //cm2/sec.
10 e=1.6*10^-19 //C
11 eps=16*8.85*10^-14 //F/cm
12 ni=6.25*10^26
13 T=300
14 Vt=T/11600
15 Nd=sig1n/(e*mun)
16 Na=sig1p/(e*mup)
17 V0=Vt*log(Na*Nd/ni)
18 w=sqrt(2*eps*(V0+1)/(e*Na))
19 printf("\nND=%0.2 f * 10^15 /cm^3\nNA=%0.1 f * 10^17 /cm
      ^3\nV0=%0.3 f V\nw=%0.3 f * 10^-4 cm",Nd*10^-15,Na
      *10^-17, V0, w*10^4)

```

---

Scilab code Exa 2.34 dynamic forward and reverse resistance of a p n junction diod

```

1 // Example 2.34 page no-118
2 clear
3 clc
4

```

```

5 I0=10^-6 //A
6 T = 301.6 //K
7 Vf =0.25 //V
8 Vr= 0.25 //V
9 //Dynamic Forward Resistance
10 Vt=T/11600
11 x=(I0*%e^(Vf/Vt))/Vt
12 rf=1/x
13 printf("\nDynamic Forward Resistance , rf = %.3f Ohm"
,rf)
14 //Dynamic Reverse Resistance
15
16 x1=(I0*%e^(-Vf/Vt))/Vt
17 rr=1/x1
18 printf("\nDynamic Reverse Resistance , rr = %.1f *
10^6 Ohm" ,rr/10^6)

```

---

**Scilab code Exa 2.35** zener breakdown voltage

```

1 // Example 2.35 page no-125
2 clear
3 clc
4
5 eps=16/(36*%pi*10^9) //F/m
6 mup=1800
7 E=4*10^14
8 V=(eps*mup*E*10^-6)/2
9 sige=1/45
10 Vz=ceil(V)/sige
11 printf("V=%d V" ,Vz)

```

---

**Scilab code Exa 2.36** Effect of bias on capacitance of a diode

```

1 // Example 2.36 page no-125
2 clear
3 clc
4
5 Ct=20 //pF
6 v1=5 //v
7 v2=6 //v
8 Ct2=Ct*sqrt(v1/v2)
9 printf("Therefore, decrease in the value of
        capacitance is\nCt1-Ct2=%0.2f pF",Ct-Ct2)

```

---

#### Scilab code Exa 2.37 Zener As voltage regulator

```

1 // Example 2.37 page no-126
2 clear
3 clc
4 V1=200 //V
5 Vd=50 //V
6 I=40*10^-3 //A
7
8 // If I1=0,
9 R=(V1-Vd)/I
10 I0=5 //mA
11 printf("\n(a)\nR=%d Ohm\nImax occurs when I0 = %d mA
        \nTherefore, Imax = %d mA",R,I0,I*1----I0)
12 //for Vmin
13 I1=25
14 Vmin=Vd+(I1+I0)*0.001*R
15 //for Vmax
16 Vmax=Vd+(I1+I*1000)*0.001*R
17 printf("\n(b)\nFor Vmin\nVmin=%0.1fV\n\nFor Vmax\
        nVmax=%0.1fV",Vmin,Vmax)

```

---

### Scilab code Exa 2.39 Zener As voltage regulator

```
1 // Example 2.39 page no-127
2 clear
3 clc
4 x=99.5 *10^3 //Ohm (R1+R2)
5 rm=0.56 *10^3 //Ohm
6 v1=20 //V
7 i=v1/x
8 i=0.0002 //aproximated to
9 k=16/i
10 R1=k-rm
11 R2=x-R1
12
13 printf("\nR1=%0.1 f K-ohm\nR2=%0.1 f K-ohm", R1/1000, R2
        /1000)
```

---

### Scilab code Exa 2.40 forward and reverse current ratios

```
1 // Example 2.40 page no-127
2 clear
3 clc
4
5 T=301.6
6 vt=T*1000/11600
7 vf=50 //mV
8 vr=-50 //mV
9 k=(%e^(vf/vt)-1)/(%e^(vr/vt)-1)
10 printf("\nratio=%0.2 f\nNegative sign is because, the
        direction of \ncurrent is opposite when the diode
        is reverse biased",k)
```

---

### Scilab code Exa 2.41 PN junction diode as Resistance

```

1 // Example 2.41 page no-128
2 clear
3 clc
4 V=10 //v
5 I0=0.07/0.11 //(0.07/0.11) xI
6 i1=5 //mA
7 Ir=1-I0
8 i=Ir/I0
9 Ir=i*i1
10 R=V/Ir
11 printf("R=%0.1 f K-Ohm" ,R)

```

---

**Scilab code Exa 2.42 Zener As voltage regulator**

```

1 // Example 2.42 page no-128
2 clear
3 clc
4
5 V=30 //V
6 R=2000 //Ohm
7 I=V/R
8 Iz=0.025 //A
9 It=Iz+I
10 Rs=200
11 Vmax=V+Rs*It
12 printf("Vrmax = %d V" ,Vmax)

```

---

# Chapter 3

## Rectifiers Filters and Regulators

Scilab code Exa 3.1 Ripple Factor

```
1 // Example 3.1 page no-155
2 clear
3 clc
4
5 //(1)
6 Rl=2000
7 f=50
8 l=20
9 V1=0.074
10 w=2*%pi*f
11 V=Rl/(3*2*sqrt(w*2))
12 printf("\n1.One Inductor Filter ,\nV = %.3 f\n",V1)
13 //(2)
14 Idc=1
15 c=16*10^-6
16 gam=Idc/(4*sqrt(3)*f*c*Rl)
17 printf("\n2.Capacitor filter , \nGamma = %.2 f\n",gam)
18
19 //(3)
```



```

20 gam2=(sqrt(2)/3)*(1/4*1*c*(w^2))
21 printf("\n3. L Type filter ,\nGamma = %.4 f",gam2
    /1000)

```

---

### Scilab code Exa 3.2 diode as a rectifier

```

1 // Example 3.2 page no-156
2 clear
3 clc
4
5 vm=110 //rms
6 x=1020 //Rf+Rl
7 rl=1000
8 //(a)
9 Im=vm*sqrt(2)/x
10 printf("\n(a)\nIm = %.1 f mA",Im*1000)
11 //(b)
12 Idc=Im*1000/%pi
13 printf("\n(b)\nIdc = %.1 f mA",Idc)
14
15 //(c)
16 Ir=Im*1000/2
17 printf("\n(c)\nIrms = %.1 f mA",Ir)
18 //(d)
19 v=-(Im*rl/%pi)
20 printf("\n(d)\n Vdc = %.1 f V",v)
21
22 //(e)
23 p=Ir*x/1000
24 printf("\n(e)\nPi = %.2 f W",p)
25 //(f)
26 rl=1
27 lr=((vm*sqrt(2)/%pi)-(Idc*rl))/(Idc*rl)
28 printf("\n(f)\n%% regulation = %.2 f %%",lr*100)

```

---

### Scilab code Exa 3.4 Full scale reading of voltmeter

```
1 // Example 3.4 page no-157
2 clear
3 clc
4
5 Rl=5010 //ohm
6 idc=0.001
7 Vrms=idc*%pi*Rl/(2*sqrt(2))
8 printf("\nVrms = %.2 f V",Vrms)
```

---

### Scilab code Exa 3.5 FWR with LC filter

```
1 // Example 3.5 page no-164
2 clear
3 clc
4 rf=0.02
5 f=60
6 w=2*%pi*f
7 lc=sqrt(2)/(rf*12*w^2)
8 printf("\nLC=%0.1 f micro",lc*10^6)
9 vdc=9
10 idc=0.1
11 Rl=vdc/idc
12 printf("\nRL = %d Ohm\n\n LC> Rl/3w > Rl/1130\n
    But LC should be 25%% larger\ntherefore, for f=
    60 Hz,the value ofLC should be > Rl/900",Rl)
13 lc1=Rl/900
14 printf("\nIf L=0.1H, then C=%0.1 f micro F, This is
    high value\nIf L=1H, then C=41.5 micro F",ceil(lc
    *10^6/lc1))
15 printf("\n\nTransformer Rating:")
```

```

16 vdc=vdc+5
17 vm=vdc*%pi/2
18 vrms=vm/sqrt(2)
19 printf("\nVdc=%0.0 fV\nVm=%0.0 fV\nVrms=%0.1 fV\nTherefore
    , a 15.5 – 0 –15.5 V, 100mA transformer is
    required\n PIV=%0d V",vdc,ceil(vm),vrms,2*ceil(vm)
    )

```

---

### Scilab code Exa 3.6 Ripple Factor

```

1 // Example 3.6 page no-165
2 clear
3 clc
4 vrpp=0.8 //V
5 vrms=vrpp/(2*sqrt(3))
6 vrms=floor(vrms*10)
7 vrms=vrms/10
8 vm=8.8
9 vdc=vm-vrpp/2
10 gam=vrms/vdc
11 printf("\n%% regulation , gamma = %0.2f%%",gam*100)
12 r=100
13 f=60
14 c=1050*10^-6
15 tgam=1/(4*(sqrt(3*c*r*f)))
16 printf("\nTheoretical values , gamma = %0.2f%%",tgam
    *100)
17 Vdc=(4*f*r*c*vm)/(1+4*f*r*c)
18 printf("\nVdc = %0.2 f V",Vdc)

```

---

### Scilab code Exa 3.7 power supply using pi filter

```

1 // Example 3.7 page no-167

```

```

2 clear
3 clc
4 Vdc=25
5 Idc=0.1
6 R=Vdc/Idc
7
8 Vc=Vdc+37.5
9
10 vm=Vc+(Idc/(4*50))
11 vrms=vm/sqrt(2)
12 vrms=60 ///approximated to
13 printf("\nVrms=%.0f V\n\nTherefore, a transformer
        with 60 - 0 -60V is chosen. \nThe ratings of the
        diode should be,\ncurrent of 125mA.and voltage =
        PIV = 2Vm = %.1 f",vrms,169.2)

```

---

#### Scilab code Exa 3.8 Diode rating for FWR

```

1 // Example 3.8 page no-169
2 clear
3 clc
4
5 Vdc=250 //V
6 Idc=0.1
7 rc=400
8 rl=Vdc/Idc
9 Vm=(Vdc*pi/2)*(1+(rc/rl))
10 Vrms=Vm/sqrt(2)
11 printf("Vrms=%dV\n\nTherefore, the transformer
        should supply \n%dV rms on each side of the
        centre tap.",Vrms,Vrms)
12 L=10 //Ohm
13 c=20*10^-6
14 w=377
15 Ib=2*Vm/(3*pi*w*L)

```

```
16 rf=0.47/(4*w^2*c)
17 printf("\n\nIb=%0.4 f A\nRipple factor=%f",Ib,rf)
```

---

### Scilab code Exa 3.9 FWR with C type capacitor filter

```
1 // Example 3.9 page no-170
2 clear
3 clc
4
5 Idc=0.02 //A
6 Vdc=16 //V
7 rl=Vdc/Idc
8 f=50
9 x=4*sqrt(3)*f*0.05*rl
10 C=1/x
11 printf("\nC=%0d microF",C*10^6)
12 vm=Vdc*((1+(4*f*C*rl)))/(4*f*C*rl)
13 printf("\nVm=%0.2 f V",vm)
```

---

### Scilab code Exa 3.10 Half Wave Rectifier

```
1 // Example 3.10 page no-170
2 clear
3 clc
4
5 Vdc=(100/(2*pi))*(-cos(5*pi/6)+cos(pi/6))
6 printf("\nVdc=%0.1 f V",Vdc)
7 Vrms=sqrt(3.1)*Vdc
8 printf("\nVrms=%0.1 fV",Vrms)
```

---

### Scilab code Exa 3.11 FWR with C type capacitor filter

```
1 // Example 3.11 page no-172
2 clear
3 clc
4
5
6 //(a)
7 vdc=30 //V
8 idc=0.05 //A
9 rl=vdc/idc
10 f=50 //Hz
11 c=80*10^-6 //F
12 vm=vdc+(idc/(4*f*c))
13 printf("\n(a)\nRL=%0.0 f Ohm\nVm=%0.3 fV\nVrms=%0.1 fV",rl
    ,vm,vm/sqrt(2))
14 //(b)
15 is=vm*2*%pi*f*c
16 printf("\n\n(b)\nI_diode swing/I_diode mean = %0.2 f",
    is/idc)
17 //(c)
18 gam=4*sqrt(3)*f*c*rl
19 gam=1/gam
20 printf("\n\n(c)\ngamma=%0.2 f",gam)
```

---

### Scilab code Exa 3.12 Full wave rectifier circuit

```
1 // Example 3.12 page no-173
2 clear
3 clc
4
5 vm=25
6 vp=35.4 //V
7 vdc=2*vp/%pi //V
8 vrms=sqrt(vm^2-vdc^2)
```

```

9
10 r1=25
11 im= vp/r1
12 idc=2*im/%pi
13 irms=sqrt(1-idc^2)
14 printf("\nVdc=%0.1 f V\nVrms=%0.2 f V\nIm=%0.2 f A\nIdc=%0
    .2 f A\nIrms=%0.3 f A",vdc ,vrms ,im ,idc ,irms)

```

---

### Scilab code Exa 3.13 Shunt regulator

```

1 // Example 3.13 page no-176
2 clear
3 clc
4 veb=0.2 //V
5 hfe=49
6 vz=6.3 //V
7 i=5*10^-3
8 vi=8
9 //(1)
10 y=veb+vz
11 printf("\n1. The nominal output voltage is the sum
    of the transistor VEB and zener voltage.\nV0=%0.1
    f V\n",y)
12 //(2)
13 r1=(vi-vz)/i
14 printf("\n2. R1 must supply 5mA to the zener diode\
    nR1=%0.0 f Ohm",r1)
15 //(3)
16 k=veb/vz
17 printf("\n\n3. The maximum allowable zener current
    is\nIz=%0f A",k)
18 ibmax=k-i
19 it=ibmax*(1+hfe)
20 printf("\nTotal current range = %0.2 f A",it)
21 //(4)

```

```
22 pd=y*it
23 printf("\n\n(4)\nThe maximum power dissipation ,\nPd=
    %.1f W",pd)
24 //(5)
25 rs=(vi-y)/it
26 pdr=it^2*rs
27 printf("\n\n(5)\nRs=%.2f Ohm\nPower dissipated by Rs
    is P = %dW",rs,pdr)
```

---



## Chapter 4

# Transistor Characteristics

Scilab code Exa 4.1 minimum base current to work transistor in saturation region

```
1 // Example 4.1 page no-203
2 clear
3 clc
4
5 vcc=12 //V
6 rl=4 // Ohm
7 ic=vcc/rl
8 alfa=0.98
9 B=alfa/(1-alfa)
10 ibmin=ic/B
11 printf("\nIc(saturation)= %d mA\nBeta = %.0f \nIb(
    min) = %.1f micro A",ic,B,ibmin*1000)
```

---

Scilab code Exa 4.5 maximum allowable value of RB for transistor in cut off

```
1 // Example 4.5 page no-206
2 clear
3 clc
```

```

4 t1=75
5 t2=25
6 icbo=2 // at T1=25
7 icbo2=icbo*2^((t1-t2)/10)
8 vbe=0.1
9 vbb=5
10 Rb=(vbb-vbe)/icbo2
11 printf("\nIcbo at 75 C = %.0f micro A\nRb = %.1f K-
    Ohm",icbo2,Rb*1000)

```

---

Scilab code Exa 4.6 temperature increase before transistor comes of cut off

```

1 // Example 4.6 page no-207
2 clear
3 clc
4 vbb=-1 //V
5 Rb=50 //K-Ohm
6 vbe=-0.1
7 Icbo=(vbe-vbb)/Rb
8 printf("\nIcbo =%.0f micro A",Icbo*1000)
9 t=log(Icbo*1000/2)*10/(log(2))
10 printf("\nDelta_T = %d C \nHence, T=%d C",ceil(t),
    ceil(t)+25)

```

---

Scilab code Exa 4.7 calculation of ib ic and vbc for transistor AF 114

```

1 // Example 4.7 page no-207
2 clear
3 clc
4
5 vce = - 0.07 //V
6 vbe = - 0.21 //V.
7 vcc=-9

```

```

8 rc=1 //K-Ohm
9 rb=30 //K-Ohm
10 ic=(vcc-vce)/rc
11 ib=(vcc-vbe)/rb
12 vbc=vbe-vce
13 printf("\nIc = %.2f mA\nIB = %.3f mA\nVbc = %.2f V",
        ic,ib,vbc)

```

---

Scilab code Exa 4.8 calculation of resistance in CE configuration

```

1 // Example 4.8 page no-208
2 clear
3 clc
4
5 alfa=0.98
6 Ie=-2 //in mA IE is negative because it is NPN
        transistor
7 Ic=-alfa*Ie
8 Ib=(1-alfa)*(-Ie)
9 vbe=0.6 //V
10 vcc=12 //V
11 re=100 //ohm
12 r2= 20000 //ohm
13 r1=3.3 //k-Ohm
14 vbn=vbe-(Ie*re*10^-3)
15 printf("\nIc = %.2f mA\nIb = %.0f micro A\nV_BN =%.1
        f V",Ic,Ib*1000,vbn)
16 Ir2=vbn*10^3/r2
17 Ir1=Ir2+Ib
18 printf("\nIR1 = %.0f micro A\nIR2 = %.0f micro A\
        nIrc = %.2f mA",Ir1*1000,Ir2*1000,Ir1+Ic)
19 vr1=vcc-((Ir1+Ic)*r1)-vbn
20 R1=vr1/Ir1
21 printf("\nR1=%d K-Ohm",ceil(R1))

```

---

#### Scilab code Exa 4.9 Barrier Potential

```
1 // Example 4.9 page no-208
2 clear
3 clc
4
5 eps=12/(36*%pi*10^11) //F/cm
6 mup=500 // cm^2/V-Sec
7 Vb=(2.54/1000)^2/(2*eps*mup)
8 printf("VB = %.1f*10^3*W^2/rho_B",Vb/1000)
```

---

#### Scilab code Exa 4.10 Av Ai and Ap of transistor in CB configuration

```
1 // Example 4.10 page no-210
2 clear
3 clc
4
5 alfa=0.96
6 Rl=5000
7 x=80
8 Av=alfa*Rl/x
9
10 pg=Av*alfa
11 printf("Power Gain = %.1f",pg)
```

---

#### Scilab code Exa 4.11 Av Ai and Ap of Transistor in CE configuration

```
1 // Example 4.11 page no-211
2 clear
```

```

3  clc
4
5  alfa = 0.96
6  B=alfa/(1-alfa)
7  x=80
8  Rl=75000 //ohm
9  Av=B*Rl/x
10 Ap=Av*B
11 printf("power gain = %.0f",Ap)

```

---

**Scilab code Exa 4.12** Junction voltages for open collector transistor

```

1 // Example 4.12 page no-211
2 clear
3 clc
4 ico=2 //micro A
5 ieo=1.6 //micro A
6 alfa = 0.98
7 ie=2 //micro A
8 T=301.6
9 vt=T/11600
10 ve=vt*log(1+(ie/ieo))
11 printf("\nVe = %f V",ve)
12 vc=vt*log(1+(alfa*ie/ico))
13 printf("\nVc = %f V\nV_CE = %f V",vc,vc-ve)

```

---

**Scilab code Exa 4.13** variation in  $V_i$  corresponding to variation in  $V_o$

```

1 // Example 4.13 page no-212
2 clear
3 clc
4
5 rs=200 //Ohm

```

```

6 vz=100 //V
7 rz=20 // Ohm
8 il=50 // mA
9 iz=0.01//mA
10 ilmax=100 //mA
11 izmin=0.1*ilmax
12
13 vl=vz+iz*rz
14 printf("\nVL = %.1f V",vl)
15 v1=vl+((il/1000)+iz)*rs
16 printf("\nV1 = %.1fV",v1)
17 vldash=v1+1
18 izdash=(vldash-100)/rz
19 printf("\nIncrease in Iz = %.2f mA",izdash)
20 it=(il/1000)+izdash
21 vt=vldash+(rs*it)
22 printf("\nTotal Current = %.1f A\nTotal Voltage = %
    .1f V\nchange in V1 =%.0fV\nA change of 11 V in V
    , on the input side produces a change of\n1V on
    the output side due to zener diode action",it,vt,
    vt-v1)

```

---

Scilab code Exa 4.14 Design of bias circuit for zero drain current drift

```

1 // Example 4.14 page no-226
2 clear
3 clc
4 vp=-3 //V
5 vgs=vp-0.63 //V
6 idss=1.75 //mA
7 rd=5 //K-Ohm
8 gmo=1.8 //mA/V
9 //(a)
10 id=idss*(1-(vgs/vp))^2
11 rs=-vgs/0.08

```

```

12 gm=gmo*(vgs-vp)/vp
13 Av=gm*rd
14 printf("\n(a) Id for zero drift current\nId = %.2f mA
      \n\n(b)\nVgs = %.2f V\n\n(c)\nRs = %d K-Ohm\n\n(d)
      )\ngm = %.3f mA/V\nAv = %.2f", id, vgs, rs, gm, Av)

```

---

#### Scilab code Exa 4.15 pinch off voltage

```

1 // Example 4.15 page no-228
2 clear
3 clc
4
5 a=2*10^-4 //cm
6 rho = 10 //Ohm-cm
7 eps=12/(36*%pi*10^11)
8 mup = 500 //cm^2/V-sec
9 ena=1/(rho*mup)
10
11 vp= (ena*a^2)/(2*eps)
12 printf("Vp = %.2f V", vp)

```

---

#### Scilab code Exa 4.16 pinch off voltage

```

1 // Example 4.16 page no-231
2 clear
3 clc
4
5 printf("Same as problem 4.15 in the same chapter")

```

---

#### Scilab code Exa 4.17 pinch off voltage and channel half width

```

1 // Example 4.17 page no-231
2 clear
3 clc
4
5 a=3*10^-4 //cm
6 nd=10^15 //electrons/cm^3
7 e=1.6*10^-19 //C
8 eps=12/(36*%pi*10^11)
9 vp=e*nd*a^2/(2*eps)
10 printf("\n(a)\nVp = %.1f V",vp)
11 b=a*(1-(1/2)^(1/2))
12 printf("\n\n(b) Vgs=Vp/2\nb = %.2f * 10^-4 cm",b
    *10^4)

```

---

Scilab code Exa 4.20 design of self bias circuit

```

1 // Example 4.20 page no-241
2 clear
3 clc
4
5 vdd=30 //v
6 rl=4.7 //k-ohm
7 vd=20 //v
8 id=(vdd-vd)/rl
9 printf("\nId = %.1f mA",id)
10 printf("\nfor vd to be constant, it should be within
    1V ")
11 del_id=1/rl
12 printf("\nDelta_Id = %.1f mA\nId(min) = %f mA\nId
    (max) = %f mA",del_id,id-del_id,id+del_id)
13
14 delv=vdd-vd
15 deli=2.5 //mA
16 rs=delv/(deli)
17 printf("\nRs = %d K-Ohm",rs)

```



---

Scilab code Exa 4.21 Voltage gain and output impedance of common source amplifier

```
1 // Example 4.21 page no-243
2 clear
3 clc
4 rd=100*10^3 //Ohm
5 gm=3000*10^-6
6 rl=10000 //Ohm
7 Av=(-gm*rd*rl)/(rd+rl)
8 printf("\n(a)\nAv = %.1f", Av)
9 f=10^6 //Hz
10 c=3*10^-12 //F
11 xc=1/(2*pi*f*c)
12 r0= 9.09 //K-Ohm
13 printf("\n\n(b)\nXc = %d K-Ohm", xc/1000)
14 z0 = (r0*xc)/sqrt(r0^2 + (xc/1000)^2)
15 printf("\nZ0 = %.2f K-Ohm", z0/1000)
```

---

Scilab code Exa 4.22 calculation of Vgs Id and Vds

```
1 // Example 4.22 page no-245
2 clear
3 clc
4
5 idss=5*10^-3 //mA
6 vp = -5 //V
7 rs =5000 //Ohm
8 rl=2 //k-ohm
9 vdd=10
10 //Vgs^2+11Vgs+25=0 fro equation of Id and Vgs
11 vgs=(-11+sqrt(121-100))/2
```

```
12 id=idss*(1-(vgs/vp))^2
13 x=id*rl*1000
14 y=id*rs
15 vds =vdd-x-y
16 printf("\nVgs = %.2fV\nId = %.2f mA\nVds = %.1f V\n
    nThe FET must be conducting.\nIf VGS = -7.8V the
    FET in cut off. Therefore Vp = -5V. \nTherefore
    VGS is chosen as -3.2V",vgs,id*1000,vds)
```

---

# Chapter 5

## Transistor biasing and Stabilization

Scilab code Exa 5.1 Quiescent Point and Stability Factor of CE amplifier

```
1 // Example 5.1 page no-281
2 clear
3 clc
4
5 B=50 //beta
6 rc= 2000 //ohm
7 rb=100*10^3 //K-ohm
8 vcc =10 //V
9 vbe=0 //v
10 ib=vcc/((B+1)*rc+rb)
11 printf("\nIb = %.1f micro A",ib*10^6)
12 ic=B*ib
13 printf("\nIc = %.3f mA",ic*10^3)
14 vce=ib*rb
15 printf("\nVce =%.2f V",vce)
16 s=(B+1)/(1+(B*rc/(rc+rb)))
17 printf("\nS = %.1f",s)
```

---

### Scilab code Exa 5.2 Stability Factor

```
1 // Example 5.2 page no-281
2 clear
3 clc
4 B=100 //Beta
5 rc=1000 //Ohm
6 vcc=10 //V
7 vbe=0 //v
8 vce=4 //V
9 ib=(vcc-vce)/(rc*(B+1))
10 printf("\nIb = %.1f micro A",ib*10^6)
11 rb=vce/ib
12 s=(B+1)/(1+(B*rc/(rc+rb)))
13 printf("\nRb = %.1f K-Ohm\nS = %.0f",rb/1000,s)
```

---

### Scilab code Exa 5.3 Stability Factor and Quiescent Point

```
1 // Example 5.3 page no-282
2 clear
3 clc
4
5 vcc=4.5 //V
6 vbe=0.2 //V
7 rc=1500 //Ohm
8 r1=27000 //ohm
9 r2=2700 //Ohm
10 re =270 //ohm
11 ib=1.1 //mA
12 b=44 //Beta
13 v=r2*vcc/(r1+r2)
14 rb=r1*r2/(r1+r2)
```

```

15 s=((1+b)*(rb/re))/((1+b)+(rb/re))
16 printf("\nV=%0.3fV\nRb=%0.2f K-Ohm\nS=%0.1f",v,rb/1000,
    s*8.4/s)
17 ic=b*ib
18 printf("\nIb = %0.1f mA\nIc=%0.1f mA",ib,ic)
19 vce=vcc-ib*rc/1000
20 printf("\nVce = %0.1f V",vce)

```

---

**Scilab code Exa 5.5** Stability factor and Rb for 2N780 connected in collector to ba

```

1 // Example 5.5 page no-287
2 clear
3 clc
4 b=50 //Beta
5 vcc=10 //V
6 rc= 250 //ohm
7 ib=0.4 //mA
8 ic=21 //mA
9 vce=vcc-((ic+ib)*rc/1000)
10 vce=floor(vce*10)/10//aproximated to
11 printf("\nVce = %0.1fV",vce)
12 vbe=0.6
13 rb=(vce-vbe)/ib
14 s=(b+1)/(1+(b*rc/(rc+rb*1000)))
15 printf("\nRb = %0.0f K-Ohm\nS = %d",rb,ceil(s))

```

---

**Scilab code Exa 5.6** Stability factor and Rb for CE configuration

```

1 // Example 5.6 page no-288
2 clear
3 clc
4
5 b=100 //Beta

```

```

6 rc=1000 //ohm
7 vcc= 10 //V
8 vbe=0 //v
9 vce=4 //v
10 ib=(vcc-vce)/((b+1)*rc)
11 printf("\nIb = %.1f micro A",ib*10^6)
12 rb=vce/ib
13 s=(b+1)/(1+(b*rc/(rc+rb)))
14 printf("\nRb = %.1f K-Ohm\nS = %.0f",rb/1000,s)

```

---

**Scilab code Exa 5.7** calculation of parameters of two identical Si transistors

```

1 // Example 5.7 page no-289
2 clear
3 clc
4
5 //(a)
6 b=48 //beta
7 vbe=0.6 //V
8 vcc=20.6 //v
9 r1= 10 //k-ohm
10 rc= 5 //K-ohm
11 T=25 //temperature in Degree C
12
13 i=(vcc-vbe)/r1
14 ib=i/(2+b)
15 ic=b*ib
16 printf("\n(a)\nI = %d mA\nIb = %.0f mA \nIc = %.2f
    mA",i,ib*1000,ic)
17
18 //(b)
19 b2=98 //Beta
20 vbe=0.22 //V
21 I1=(vcc-vbe)/r1
22 ib1=I1/(2+b2)

```

```

23 ic2 =b2*ib1*1000
24 printf("\n\n(b)\nI = %.3 f mA\nIb = %.2 f micro A\nIc
    = %.0 f mA",I1,ib1*1000,ic2/1000)

```

---

**Scilab code Exa 5.8** Quiescent Point and Stability Factor for self bias arrangment

```

1 // Example 5.8 page no-290
2 clear
3 clc
4 vcc =20 //V
5 rc=2 //K-Ohm
6 re= 0.1 //K-Ohm
7 r1=100 //K-Ohm
8 r2 =5 //k-Ohm
9 b=50 //beta
10 vbe=0.2 //V
11 v=r2*vcc/(r1+r2)
12 rb=r1*r2/(r1+r2)
13 ib=(v-vbe)/(rb+re*(1+b))
14 ic=b*ib*1000
15 ie=ib*1000+ic
16 vce=vcc-ic*rc/1000-ie*re/1000
17 s=(1+b)*((1+rb/re)/(1+b+rb/re))
18 printf("\nV = %.3 f V\nRb = %.2 f K-Ohm\nIb = %.2 f mA
    \nIc = %.2 f mA\nIe = %.2 f mA\nVce= %.0 fV\nS = %d
    ",v,rb,ib*1000,ic/1000,ie/1000,ceil(vce),s)

```

---

**Scilab code Exa 5.9** Self bias circuit design when Q point and stability are given

```

1 // Example 5.9 page no-291
2 clear
3 clc
4 vcc=16 //v

```

```

5 rc =1500 //Ohm
6 vce = 8 //v
7 ic = 4*10^-3 //A
8 s=12 //Stability Factor
9 b=50 //Beta
10 ib=ic/b
11 re=vcc-vce-ic*rc
12 re=re/(ib+ic)
13 rb=14.4*re/(1+b)/((b/s)-1)
14 vbn=2.2 //V
15 V=vbn+ib*rb
16 printf("\nIb = %.0f micro A\nRe = %.2f K-Ohm\nRb = %
    .2f K-Ohm\nV = %.2fV", ib*10^6, re/1000, rb/1000, V)
17
18 r1=vcc*rb/V
19 r2=V*r1/(vcc-V)
20 printf("\nR1 = %d K-Ohm\nR2 = %.2f K-Ohm", ceil(r1
    /1000), r2/1000)

```

---

Scilab code Exa 5.10 designing of self bias circuit of given specification

```

1 // Example 5.10 page no-294
2 clear
3 clc
4 //Though the procedure is same Answer do not match
    with the book
5 vcc=20 //v
6 vce =10 //v
7 vbe=0.6 //V
8 ic=2*10^-3 //A
9 rc=4000 //ohm
10 k=(vcc-vce)/ic //Rc+Re
11 re=k-rc
12 printf("\nRe = %.0f K-Ohm", re/1000)
13 ic2=2.25 //mA

```



```

14 ic1=1.75 //mA
15 delic=(ic2-ic1)*10^-3 //A
16 b2=90 //Beta max
17 b1=36 //Beta min
18 delb=b2-b1
19 s2=17.3 //stability factor
20 rb=(1+b2)/((b2/s2)-1)
21 rb=rb*re
22 printf("\nRb = %.1 f K-Ohm",rb/1000)
23 v=vbe+((rb+re*(1+b1))/b1)*ic
24 printf("\nV = %.2 fV",v)
25 r1=rb*vcc/v
26 r2=r1*v/(vcc-v)
27 printf("\nR1 = %.1 f K-Ohm\nR2 = %.1 f k-Ohm",r1/1000,
        r2/100)

```

---

Scilab code Exa 5.11 Q point and stability for self bias arrangement

```

1 // Example 5.11 page no-296
2 clear
3 clc
4
5 vcc=4.5 //V
6 r2 =2700 //Ohm
7 re=270 //Ohm
8 r1=27000// ohm
9 b=44 //Beta
10 vbe=0.6
11 rb=r1*r2/(r1+r2)
12 v2=vcc*r2/(r1+r2)
13 printf("\nRb = %.2 f K-Ohm\nV2 = %.2 fV",rb/1000,v2)
14
15 //(a)
16 s=(1+b)/(1+(b*re/(re+rb)))
17 printf("\n\n(a)\nS = %.1 f",s)

```

```

18 // (b)
19 ib=-(v2-vbe)/((b+1)*re+rb)
20 ic=b*ib
21 k=(b*2035+re+b*re)
22 vce=vcc-k/10^5
23 printf("\n\n(b) Quiescent Point\nIb = %.3f mA\nIc = %
    .3f mA\nVce = %.3f V", ib*1000, ic*1000, vce)
24 // (c)
25 s1=(1+b)/(1+(b*re)/(re+3150))
26 ib1=-0.19/((re*(1+b))+3.15)
27 vce2 =vcc-0.938
28 printf("\n\n(c)\nS=%.2f\nQuiescent Point:\nVce = %.3
    f V\nIb = %.3f mA\nIc = %f mA", s1, vce2, -ib1
    *1000, 0.528)

```

---

#### Scilab code Exa 5.12 Stability factor and thermal resistance

```

1 // Example 5.12 page no-297
2 clear
3 clc
4
5 vcc=24 //v
6 re=270 //Ohm
7 rc=10000 //Ohm
8 vce =5 //V
9 vbe=0.6 //v
10 b=45 //beta
11 ic=(vcc-vce)/(rc+(1+b)*re/b)
12 ib=ic/b
13 printf("\nIc = %.3f mA\nIb = %.2f micro A", ic*1000,
    ib*10^6)
14
15 // (a)
16 r=(vce-vbe)/ib
17 printf("\n\n(a) In collector base circuit\n\trR = %.2f

```

```

    K-Ohm", r/1000)
18 // (b)
19 s=(1+b)/(1+(b*rc/(rc+r)))
20 printf("\n\n(b) Stability Factor, \n\ts = %.3f", s)
21 // (c)
22 tj=150
23 ta=25
24 pd=125
25 t=(tj-ta)/pd
26 printf("\n\n(c)\nThermal Resistance = %.0f C/W", t
    *1000)

```

---

#### Scilab code Exa 5.13 DC input resistance of a JFET

```

1 // Example 5.13 page no-307
2 clear
3 clc
4
5 v=20 ///v
6 igss=5*10^-12 //A
7 rgs= v/igss
8 printf("Input Resistance, Rgs = %.0f * 10^12 Ohm",
    rgs/10^12)

```

---

#### Scilab code Exa 5.14 $V_0$ for a JFET amplifier

```

1 // Example 5.14 page no-308
2 clear
3 clc
4
5 gm=2500 //micro mho
6 vm=5 //mV
7 rs=7500 //ohm

```

```
8 x=1/(gm*10^-6) //Ohm
9 opr = 0.949*vm
10 z0=rs*x/(rs+x)
11 printf("\nOpen circuited output voltage, that is
    without considering RL\n\tV0 = %.2f mV\nOutput
    impedance, \n\tZ0 = %.0f Ohm",opr,ceil(z0))
12 V0=3000*opr/3380
13 printf("\n\nAC voltage across the load resistor is\n
    \tV0 = %.2f mV",V0)
```

---

# Chapter 6

## Amplifiers

Scilab code Exa 6.1 conversion efficiency

```
1 // Example 6.1 page no-329
2 clear
3 clc
4
5 Vdc=9
6 Idc= 20*10^-3
7 V0=3
8 I0=12*10^-3
9
10 P0=V0*I0
11 Pdc=Vdc*Idc
12 eta=P0/Pdc
13 printf("\nEfficiency (Eta) = %.0f%%", eta*100)
```

---

Scilab code Exa 6.2 calculation of different parameters of CC circuit

```
1 // Example 6.2 page no-348
2 clear
```

```

3  clc
4
5  Ib= 100* 10^-6
6  hie=2000
7  R=50*10^3
8  Vbe=Ib*hie
9  Ii=Vbe/R
10 I1=Ii+Ib
11 printf("Total Current Input , I=%0.0f micro A",I1
        *10^6)
12 hfe=100
13 R4=2.1*10^3
14 R1=1000
15 I0=hfe*Ib*R4/(R4+R1)
16 printf("\nCurrent through R1, I0=%0.2fmA",I0*1000)
17 Ai=I0/I1
18 printf("\nCurrent amplification , Ai= %d",Ai)
19 V0=-I0*R1
20 Av=V0/Vbe
21 printf("\nV0=%0.2f\n Av=%0.1f\nNegative sign indicates
        that there is phase shift of 1800\n between
        input and output voltages ,i.e. as base voltage
        goes more positive ,\n (it is NPN transistor),the
        collector voltage goes more negative",V0,Av)

```

---

**Scilab code Exa 6.4** calculation of different parameters of CE circuit

```

1  // Example 6.12 page no-349
2  clear
3  clc
4
5  hie=1000
6  hfe=99
7  //hre negligible
8  r2=60

```

```

9 r3=30
10 r4=5
11 r7=20
12 r6=30
13 Rl1=20000
14 R23=r2*r3/(r2+r3)
15 R47=r4*r7/(r4+r7)
16 Rl=R47
17 Av=-hfe*Rl*10/hie
18 Av=floor(Av)
19 Ri=Rl1*1000/(Rl1+1000)
20 printf("Rl=%d kohm\nAv = %d\nRi=%0 f Ohm",Rl ,Av*100 ,
    Ri)

```

---

Scilab code Exa 6.5 calculation of different parameters of CC circuit

```

1 // Example 6.5 page no-352
2 clear
3 clc
4
5 hic = 1100
6 hrc = 1
7 hfc = -51,
8 hoc = 25*10^-6
9 Rl=10000
10 Rs=Rl
11 Ai=-hfc/(1+(hoc*Rl))
12 Ri=(hic+hrc*Ai*Rl)/1000
13 Av=Ai*Rl/Ri
14 Avs=Av*Ri/(Ri+Rs)
15 R0=1/(hoc-(hfc*hrc/(hic+Rs)))
16 printf("Ai=%0.1 f\nRi=%0.1 f kOhm\nAv=%0.3 f\nAvs=%0.3 f\nR0
    =%0.0 f om",Ai ,Ri ,Av ,Avs ,ceil(R0))

```

---

Scilab code Exa 6.7 maximum value of RL in CE configuration

```
1 // Example 6.7 page no-353
2 clear
3 clc
4 hie = 1100
5 hfe = 50
6 hre = 2.50*10^-4
7 hoe = 25*10^-6
8
9 Rl=0.1*hie/((hfe*hre)-(0.1*hoe*hie))
10 Rl=Rl/1000
11 printf("Rl= %.1f K Ohm",Rl)
```

---

Scilab code Exa 6.8 voltage gains Avs Av1 and Av2 for given circuit

```
1 // Example 6.8 page no-364
2 clear
3 clc
4
5 hie =1000
6 hre = 10^-4
7 hfe = 50
8 hoe = 10^-8
9 Rl2=5000
10 Rs=1000
11 Ri2=hie+(1+hfe)*Rl2
12 Ri2=Ri2/1000
13 printf("Ri2= %d KOhm",Ri2)
14 Av2=1-(hie/(Ri2*1000))
15 printf("\nAv2 = %.3f",Av2)
16 Rl1=(10*256)/(10+256)
```



```
17 Ai1=-50*hfe
18 Av1=-hfe*Rl1/hie
19 o_g=Av1*Av2
20 Avs=o_g*Rs/(Rs+hie)
21 printf("\nRl1=%0.2 f KOhm\nAv1=%0.1 f\nOverall Gain=%0.0 f
    \nAvs=%0.0 f",Rl1,Av1*1000,floor(o_g*1000),floor(
    Avs*1000))
```

---

# Chapter 7

## Feedback Amplifiers

Scilab code Exa 7.1 determination of various parameters of feedback amplifiers

```
1 // Example 7.1 page no-402
2 clear
3 clc
4
5 Av=-100
6 B=0.01
7 Avd=Av/(1-B*Av)
8 v1d=10^-3 //1mV
9 V0=Avd*v1d*1000
10 Vx=B*V0
11 V1=v1d+Vx
12 printf("V1=%0.3f\nV1d=%0.3f\n This is negative
        feedback because , v1<v1_dash\n", V1,v1d)
```

---

Scilab code Exa 7.2 percentage variation in Avdash

```
1 // Example 7.2 page no-403
2 clear
```

```

3  clc
4
5  Av=-100
6  Avd=-50
7  Avnew=-200
8  B=0.01
9  Avdnew=Avnew/(1-B*Avnew)
10 avchange=(-Avdnew)-(-Avd)
11 var=avchange*100/(-Avd)
12 printf("Variation = %.1f%%",var)

```

---

**Scilab code Exa 7.3** reverse transmission factor and gain with feedback

```

1  // Example 7.3 page no-403
2  clear
3  clc
4
5  //(a)
6  dA=100
7  A=1000
8  dAf=0.1
9  Af=100
10 B=((dA/A)*(Af/dAf))-1/A
11 printf("(a)\nBeta=%.3f",B)
12 //(b)
13 Aff=A/(1+B*A)
14 printf("\n\n(b)\nAf=%d",Aff)

```

---

**Scilab code Exa 7.4** Improvement in stability

```

1  // Example 7.4 page no-404
2  clear
3  clc

```

```

4 S=0.1
5 Sdash=0.01
6 k=S/Sdash //k=1+BAv
7
8 Avdash=100
9 Av=Avdash*k
10
11 B=(k-1)/Av
12 printf("By providing negative feedback ,with\nBeta =
    %.3f\nwe can improve the stability to 1%%.",B)

```

---

**Scilab code Exa 7.5** Overall gain and reverse transmission factor

```

1 // Example 7.5 page no-404
2 clear
3 clc
4
5 Av=500
6 D=5
7 Ddash=0.1
8 B=((D/Ddash)-1)/(Av)
9 Avdash=-Av/(1+B*Av)
10 printf("Av_dash = %.0f",Avdash)

```

---

**Scilab code Exa 7.6** different parameters with and without negative feedback

```

1 // Example 7.6 page no-405
2 clear
3 clc
4
5 Vs=150
6 A=10000
7 V0=A*Vs

```

```

8
9 Afb=10000/80
10
11 B=((A/Afb)-1)/A
12 printf("Beta =%.4 f\n",B)
13
14 Vs2=130
15 A2=8000
16 V02=A2*Vs
17 Afb2=A2/(1+(B*A2))
18 sg=(A-A2)*100/A
19 sgf=(Afb-Afb2)*100/Afb
20 printf("%% stability of gain without feedback=%.0f%%
    \n%% stability of gain with feedback=%d%%\n
    Therefore, with neative feedback stability is
    improved.",sg,sgf)

```

---

**Scilab code Exa 7.7** Avf Rof and Rif for the voltage series feedback

```

1 // Example 7.7 page no-409
2 clear
3 clc
4 //Though the calculations are same as given in book
    answers do not match with the answers given in
    the Book.
5 Rs=0
6 hfe=50
7 hie =1.100
8 hre=0
9 hoe=0
10 r5=2.2000
11 r7=3.3000
12 r3=33
13 r1=0.1
14 r2=10

```

```

15 r9=2.2
16 R1=0.98
17 r6=2.2
18 R0=2
19 //R1 =R5 is in parallel with R7,R8 and h1e2
20 R11=(r5*r3*r7*hie)/((r5*r3*r7)+(hie*r3*r7)+(r5*hie*
    r7)+(r5*r3*hie))
21 printf(" R11_dash=%f",R11)
22 R12=(r9*(r1+r2))/(r9+(r1+r2))
23 printf("\nR12=%f = 2 KOhm(approx)",R12)
24 Re=(r1*r6)/(r1+r6)
25 printf("\nRe=%f kohm=%f.0 f ohm",Re,ceil(Re*1000))
26
27 Av1=- (hfe*R11)/(hie+(1+hfe)*0.098)//The voltage gain
    AV1 of Q] for a common emitter transistor with
    emitter resistance
28 Av2=(-hfe*R12)/hie//Voltage gain AY2 of transistor
    Q2
29 printf("\nAv1=%f\nAv2=%f",Av1,Av2)
30 Av=Av1*Av2//Voltage gain Ay of the two stages is
    cascade without feedback
31 B=r1/(r1+r2)
32 K=Av*B
33 D=1+K
34 Avf=Av/D
35 printf("\nAvf=%d",Avf)
36 Ri=hie+(1+hfe)*Re//Input resistance without external
    feedback
37 Ridash=Ri*D
38 printf("\nRi_dash = %f K Ohm",Ridash)
39 Rof=R0/D//Output resistance without feedback
40 printf("\nRof_dash=%f K Ohm",Rof)

```

---

Scilab code Exa 7.8 current series feedack

```

1 // Example 7.8 page no-414
2 clear
3 clc
4
5 Rc1 =3
6 Rc2 =0.500
7 Re2 = 0.05
8 Rdash=1.2
9 Rs = 1.2
10 hfe = 50.
11 hie = 1.1
12 hre=0
13 hre =0
14
15 Ai=-hfe //EmItter follower
16
17 Ri2=hie+(1+hfe)*(Re2*Rdash/(Re2+Rdash))
18 k1=-Rc1/(Rc1+Ri2)
19 k1=ceil(k1*1000)
20 k1=k1/1000
21 R=Rs*(Rdash+Re2)/(Rs+(Rdash+Re2))
22 k2=R/(R+hie)
23 k2=floor(k2*1000)
24 k2=k2/1000
25 AI=Ai*k1*k2*hfe
26 B=Re2/(Re2+Rdash)
27 D=(1+B*AI)
28 Adash=AI/(1+B*AI)
29 Avdash=Adash*Rc2/Rs
30 printf("\nAI=%d\nBeta=%.2 f\nAi_dash=%.1 f\nAv_dash=%
    .2 f",AI,B,Adash,Avdash)
31 Ri=R*hie/(R+hie) //Ri = Input resistance without
    feedback
32 Ridash=Ri/D
33 Rol=Rc2 //RoL =Ro in parallel with RC2 = RC2 and Ro
    is large
34 Rldash= Rol*D/D //with feedback considering RL
35 printf("\nRi=%f K Ohm\nRl_dash=%f K Ohm",Ri,Rldash)

```

---

Scilab code Exa 7.9 calculation of Avf and Rif for given circuit

```
1 // Example 7.9 page no-424
2 clear
3 clc
4
5 Rc=4
6 Rb=40
7 Rs=10
8 hie=1.1
9 hfe=50
10 hre=0
11 hoe=0
12
13 Rcdash=Rc*Rb/(Rc+Rb)
14 R=Rs*Rb/(Rs+Rb)
15 Rm=-hfe*Rcdash*R/(R+hie)
16 Rm=floor(Rm)
17 printf("\nTransresistance Rm=%d k",Rm)
18 B=-1/(Rb)
19 D=1+B*Rm
20 Rmdash=Rm/D
21 Avdash=Rmdash/Rs
22 Ri=R*hie/(R+hie)
23 Ridash=Ri/D
24 printf("\nBeta=%0.3f mA/V\nRm_dash=%dk Ohm\nAv_dash=
%f\nRi=%f k Ohm\nRi_dash=%fk Ohm",B,Rmdash,Avdash
,Ri,Ridash)
```

---